

### FEATURES

- Low Zener impedance
- High stability and high reliability
- Ideally suited for automated assembly processes
- The plastic material carries U/L recognition 94V-0

### MECHANICAL DATA

- **Package:** SOT-23 small outline plastic package
- **Polarity:** See diagram
- **Mounting position:** any

### MAXIMUM RATINGS (T<sub>a</sub>=25°C Unless otherwise specified)

PARAMETERS	SYMBOLS	VALUE	UNITS
Power Dissipation	P <sub>D</sub>	300	mW
Forward Voltage @I <sub>F</sub> =10mA	V <sub>f</sub>	0.9	V
Storage temperature range	T <sub>STG</sub>	-65 to + 150	°C
Thermal resistance junction to ambient air*	R <sub>thA</sub>	417	°C/W

\*Device mounted on FR-4 PC board with recommended pad layout, on page 4.

### ELECTRICAL CHARACTERISTICS (T<sub>a</sub>=25°C Unless otherwise specified)

Type Number	Code	Zener Voltage Range (Note 1)				Maximum Zener Impedance (Note 2)			Maximum Reverse Current		Temperature Coefficient of Zener voltage @ I <sub>ZT</sub> =5mA mV/°C	
		V <sub>Z</sub> @I <sub>ZT</sub>			I <sub>ZT</sub>	Z <sub>ZT</sub> @I <sub>ZT</sub>	Z <sub>ZK</sub> @I <sub>ZK</sub>	I <sub>ZK</sub>	I <sub>R</sub>	V <sub>R</sub>	Min	Max
		Nom(V)	Min(V)	Max(V)	(mA)	(Ω)	(mA)	(μA)	(V)			
BZX84C2V4	Z11	2.4	2.20	2.60	5	100	600	1.0	50	1.0	-3.5	0
BZX84C2V7	Z12	2.7	2.5	2.9	5	100	600	1.0	20	1.0	-3.5	0
BZX84C3V0	Z13	3.0	2.8	3.2	5	95	600	1.0	10	1.0	-3.5	0
BZX84C3V3	Z14	3.3	3.1	3.5	5	95	600	1.0	5	1.0	-3.5	0
BZX84C3V6	Z15	3.6	3.4	3.8	5	90	600	1.0	5	1.0	-3.5	0
BZX84C3V9	Z16	3.9	3.7	4.1	5	90	600	1.0	3	1.0	-3.5	0
BZX84C4V3	Z17	4.3	4.0	4.6	5	90	600	1.0	3	1.0	-3.5	0
BZX84C4V7	Z1	4.7	4.4	5.0	5	80	500	1.0	3	2.0	-3.5	0.2
BZX84C5V1	Z2	5.1	4.8	5.4	5	60	480	1.0	2	2.0	-2.7	1.2

Note: 1. Test with pulse, period=5ms, pulse width=300us.

2. F=1KHz

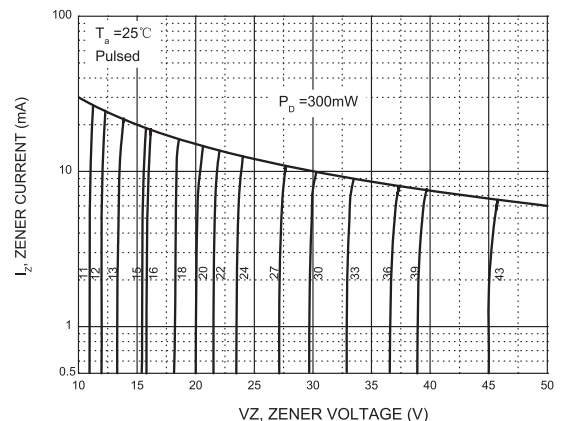
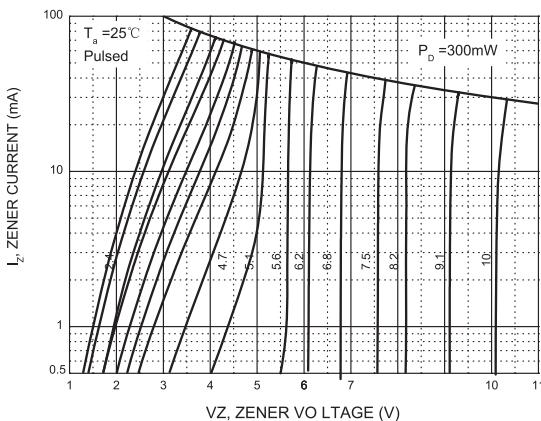
Type Number	Code	Zener Voltage Range (Note 2)				Maximum Zener Impedance (Note 3)			Maximum Reverse Current		Temperature Coefficient of Zener voltage @ I <sub>ZT</sub> =5mA	
		V <sub>Z</sub> @I <sub>ZT</sub>			I <sub>ZT</sub>	Z <sub>ZT</sub> @I <sub>ZT</sub>	Z <sub>ZK</sub> @I <sub>ZK</sub>	I <sub>ZK</sub>	I <sub>R</sub>	V <sub>R</sub>	mV/°C	
		Nom(V)	Min(V)	Max(V)	(mA)	(Ω)		(mA)	(μA)	(V)	Min	Max
BZX84C5V6	Z3	5.6	5.2	6.0	5	40	400	1.0	1	2.0	-2.0	2.5
BZX84C6V2	Z4	6.2	5.8	6.6	5	10	150	1.0	3	4.0	0.4	3.7
BZX84C6V8	Z5	6.8	6.4	7.2	5	15	80	1.0	2	4.0	1.2	4.5
BZX84C7V5	Z6	7.5	7.0	7.9	5	15	80	1.0	1	5.0	2.5	5.3
BZX84C8V2	Z7	8.2	7.7	8.7	5	15	80	1.0	0.7	5.0	3.2	6.2
BZX84C9V1	Z8	9.1	8.5	9.6	5	15	100	1.0	0.5	6.0	3.8	7.0
BZX84C10	Z9	10	9.4	10.6	5	20	150	1.0	0.2	7.0	4.5	8.0
BZX84C11	Y1*	11	10.4	11.6	5	20	150	1.0	0.1	8.0	5.4	9.0
BZX84C12	Y2*	12	11.4	12.7	5	25	150	1.0	0.1	8.0	6.0	10.0
BZX84C13	Y3	13	12.4	14.1	5	30	170	1.0	0.1	8.0	7.0	11.0
BZX84C15	Y4	15	13.8	15.6	5	30	200	1.0	0.1	10.5	9.2	13.0
BZX84C16	Y5	16	15.3	17.1	5	40	200	1.0	0.1	11.2	10.4	14.0
BZX84C18	Y6*	18	16.8	19.1	5	45	225	1.0	0.1	12.6	12.4	16.0
BZX84C20	Y7	20	18.8	21.2	5	55	225	1.0	0.1	14.0	14.4	18.0
BZX84C22	Y8	22	20.8	23.3	5	55	250	1.0	0.1	15.4	16.4	20.0
BZX84C24	Y9	24	22.8	25.6	5	70	250	1.0	0.1	16.8	18.4	22.0
BZX84C27	Y10	27	25.1	28.9	2	80	300	0.5	0.1	18.9	21.4	25.3
BZX84C30	Y11*	30	28.0	32.0	2	80	300	0.5	0.1	21.0	24.4	29.4
BZX84C33	Y12	33	31.0	35.0	2	80	325	0.5	0.1	23.1	27.4	33.4
BZX84C36	Y13	36	34.0	38.0	2	90	350	0.5	0.1	25.2	30.4	37.4
BZX84C39	Y14	39	37.0	41.0	2	130	350	0.5	0.1	27.3	33.4	41.2
BZX84C43	Y15	43	40.0	46.0	2	100	700	1	0.1	32	10	12

- Notes: 1. Valid provided that device terminals are kept at ambient temperature.  
 2. Tested with pulses, period=5ms,pulse width =300μs.  
 3. F= 1kHz.

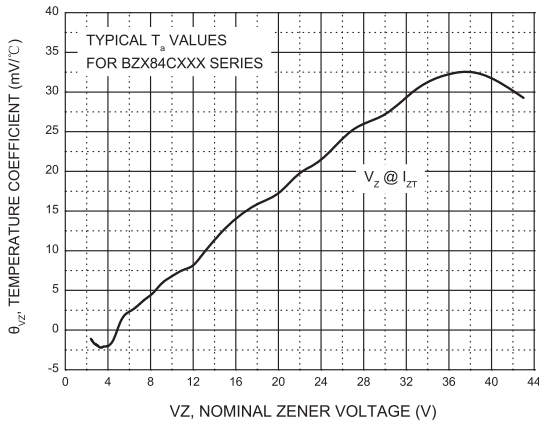
**CHARACTERISTICS (Typical)**

**FIG1.-Zener Characteristics(V<sub>Z</sub> Up to 10 V)**

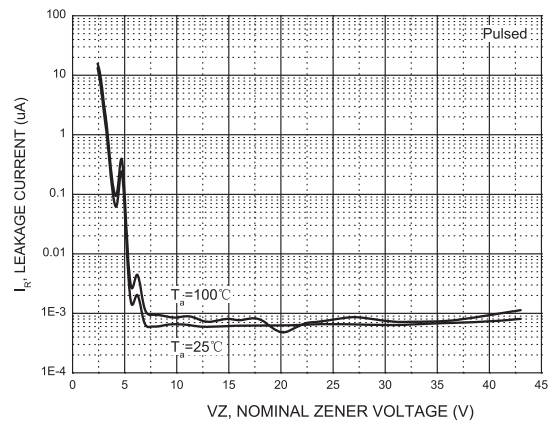
**FIG.2-Zener Characteristics(11 V to 43 V)**



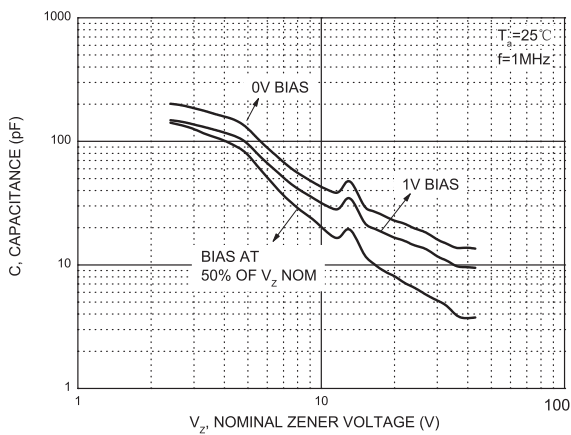
**FIG.3- Temperature Coefficients**



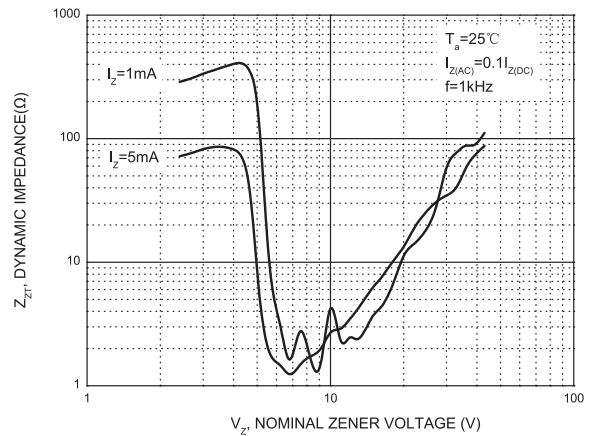
**FIG.4-Typical Leakage Current**



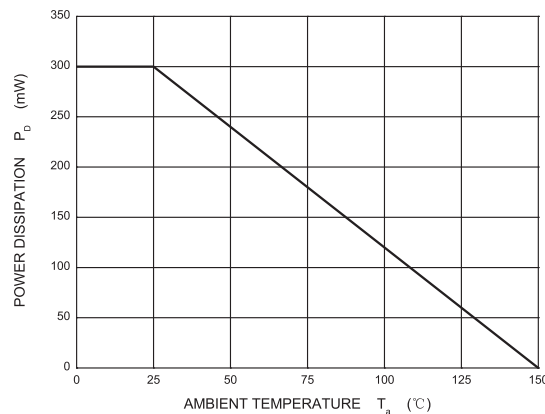
**FIG.5-Typical C Capacitance**



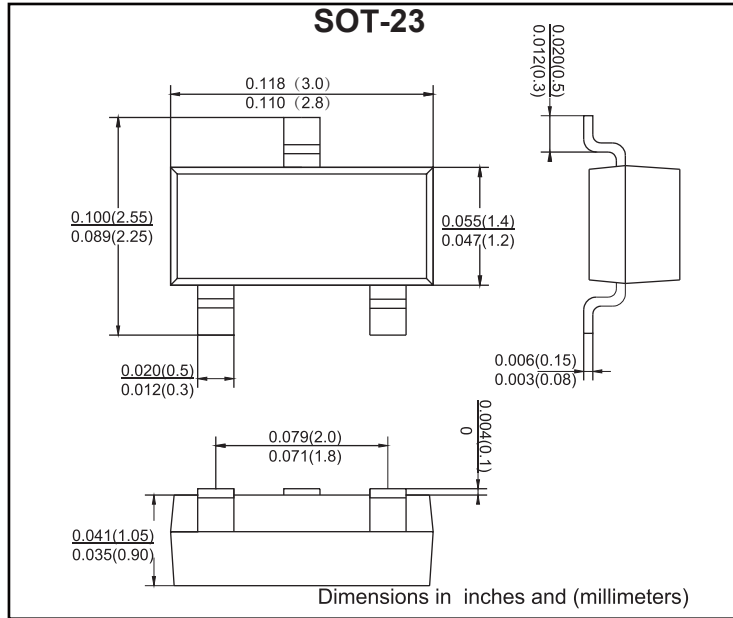
**FIG.6-Effect of Zener Voltage on Zener Impedance**



**FIG.7-Power Derating Curve**



■ **SOT-23 PACKAGE OUTLINE DIMENSIONS**



■ **SOT-23 SUGGESTED PAD LAYOUT**

